

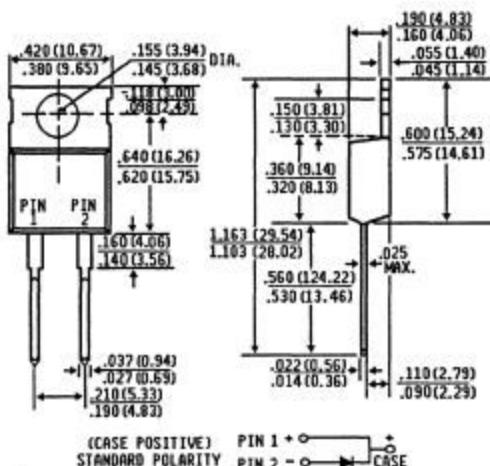
# RS8AT THRU RS8MT

**HIGH CURRENT FAST SWITCHING PLASTIC RECTIFIER**  
**VOLTAGE - 50 to 1000 Volts    CURRENT - 8.0 Amperes**

## FEATURES



### TO-220



Dimensions in inches and (millimeters)

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-O
- ◆ High forward surge capability
- ◆ High current operation
- ◆ Low forward voltage drop
- ◆ Fast switching for high efficiency
- ◆ Glass passivated chip junction
- ◆ High temperature soldering guaranteed: 265°C/10 seconds/.25", (6.35mm) lead lengths at 5 lbs., (2.3kg) tension

## MECHANICAL DATA

**Case:** JEDEC TO-220 molded plastic

**Terminals:** Plated Leads solderable per MIL-STD-202, Method 208

**Polarity:** As marked

**Weight:** .08 ounces, 2.224 grams

**Mounting Position:** Any

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

SYMBOLS	RS8 AT	RS8 BT	RS8 DT	RS8 GT	RS8 JT	RS8 KT	RS8 MT	UNITS	
Maximum Recurrent Peak Reverse Voltage	VRMM	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at $T_C = 100^\circ\text{C}$	I <sub>(AV)</sub>					8.0			Amps
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>				150				Amps
Maximum Instantaneous Forward Voltage at 8.0A	V <sub>F</sub>			1.3					Volts
Maximum Reverse Current $T_J = 25^\circ\text{C}$ at Rated DC Blocking Voltage $T_C = 100^\circ\text{C}$	I <sub>R</sub>			10.0					μA
Maximum Reverse Recovery Time (Note 2) $T_J = 25^\circ\text{C}$	T <sub>RR</sub>		150	200	250	500			ns
Typical Junction Capacitance (Note 1)	C <sub>J</sub>			55					pf
Typical Thermal Resistance (Note 3)	R <sub>θJC</sub>			3.0					°C/W
Operating and Storage Temperature Range,	T <sub>J,TSTG</sub>			-50 to +150					°C

### NOTES:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0 V<sub>dc</sub>.
2. Reverse Recovery Test Conditions : I<sub>F</sub> = 0.5A, I<sub>R</sub> = 1.0A, I<sub>RR</sub> = .25A.
3. Thermal Resistance from Junction to Case attached to heat sink.